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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Discontinued at Digi-Key
Core Processor	F ² MC-16FX
Core Size	16-Bit
Speed	56MHz
Connectivity	CANbus, EBI/EMI, I ² C, LINbus, SCI, UART/USART
Peripherals	DMA, LCD, LVD, LVR, POR, PWM, WDT
Number of I/O	96
Program Memory Size	288KB (288K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 16x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	120-LQFP
Supplier Device Package	120-LQFP (16x16)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/mb96f386rsbpmc-gse2

1. Product Lineup

Features		MB96V300B	MB96(F)38x
Product type		Evaluation sample	Flash product: MB96F38x Mask ROM product: MB9638x
Product options			
YS		NA	Low voltage reset persistently on / Single clock
RS			Low voltage reset can be disabled / Single clock
YW			Low voltage reset persistently on / Dual clock
RW			Low voltage reset can be disabled / Dual clock
TS			indep. 32KB Flash / Low voltage reset persistently on / Single clock
HS			indep. 32KB Flash / Low voltage reset can be disabled / Single clock
TW			indep. 32KB Flash / Low voltage reset persistently on / Dual clock
HW			indep. 32KB Flash / Low voltage reset can be disabled / Dual clock
Flash/ROM	RAM		
128KB	6KB	ROM/Flash memory emulation by external RAM, 92KB internal RAM	MB96384Y ^{*1} , MB96384R ^{*1}
160KB	8KB		MB96385Y ^{*1} , MB96385R ^{*1} , MB96F385Y ^{*1} , MB96F385R ^{*1}
288KB	16KB		MB96F386Y, MB96F386R
416KB	16KB		MB96F387Y, MB96F387R
576KB [Flash A: 544KB, Flash B: 32KB]	28KB		MB96F388T ^{*1} , MB96F388H ^{*1}
832KB [Flash A: 544KB, Flash B: 288KB]	32KB		MB96F389Y ^{*1} , MB96F389R ^{*1} ,
Package		BGA416	FPT-120P-M21
DMA		16 channels	7 channels
USART		10 channels	5 channels
I2C		2 channels	1 channel
A/D Converter		40 channels	16 channels
A/D Converter Reference Voltage switch		yes	Only for MB96F386Y, MB96F386R, MB96F387Y, MB96F387R
16-bit Reload Timer		6 channels + 1 channel (for PPG)	4 channels + 1 channel (for PPG)
16-bit Free-Running Timer		4 channels	2 channels
16-bit Output Compare		12 channels	4 channels

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I/O map MB96(F)38x (Sheet 22 of 30)

Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
00061F _H	LCD - Output Enable Register 3 (Seg 31-24)	LCDER3	-	R/W
000620 _H	LCD - Output Enable Register 4 (Seg 39-32)	LCDER4	-	R/W
000621 _H	LCD - Output Enable Register 5 (Seg 47-40)	LCDER5	-	R/W
000622 _H	LCD - Output Enable Register 6 (Seg 55-48)	LCDER6	-	R/W
000623 _H	LCD - Output Enable Register 7 (Seg 63-56)	LCDER7	-	R/W
000624 _H	LCD - Output Enable Register 8 (Seg 71-64)	LCDER8	-	R/W
000625 _H	Reserved	-	-	-
000626 _H	LCD - Output Enable Register V (Vx)	LCDVER	-	R/W
000627 _H	LCD - Extended Control Register	LECR	-	R/W
000628 _H	LCD - Common pin switching register	LCDCMR	-	R/W
000629 _H	LCD - Control Register	LCR	-	R/W
00062A _H	LCD - Data register for Segment 1-0	VRAM0	-	R/W
00062B _H	LCD - Data register for Segment 3-2	VRAM1	-	R/W
00062C _H	LCD - Data register for Segment 5-4	VRAM2	-	R/W
00062D _H	LCD - Data register for Segment 7-6	VRAM3	-	R/W
00062E _H	LCD - Data register for Segment 9-8	VRAM4	-	R/W
00062F _H	LCD - Data register for Segment 11-10	VRAM5	-	R/W
000630 _H	LCD - Data register for Segment 13-12	VRAM6	-	R/W
000631 _H	LCD - Data register for Segment 15-14	VRAM7	-	R/W
000632 _H	LCD - Data register for Segment 17-16	VRAM8	-	R/W
000633 _H	LCD - Data register for Segment 19-18	VRAM9	-	R/W
000634 _H	LCD - Data register for Segment 21-20	VRAM10	-	R/W
000635 _H	LCD - Data register for Segment 23-22	VRAM11	-	R/W
000636 _H	LCD - Data register for Segment 25-24	VRAM12	-	R/W
000637 _H	LCD - Data register for Segment 27-26	VRAM13	-	R/W
000638 _H	LCD - Data register for Segment 29-28	VRAM14	-	R/W
000639 _H	LCD - Data register for Segment 31-30	VRAM15	-	R/W
00063A _H	LCD - Data register for Segment 33-32	VRAM16	-	R/W
00063B _H	LCD - Data register for Segment 35-34	VRAM17	-	R/W
00063C _H	LCD - Data register for Segment 37-36	VRAM18	-	R/W

I/O map MB96(F)38x (Sheet 23 of 30)

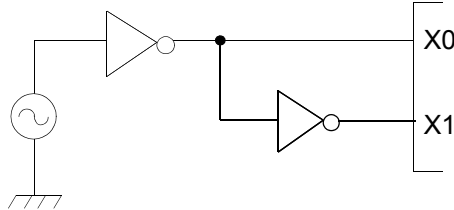
Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
00063D _H	LCD - Data register for Segment 39-38	VRAM19	-	R/W
00063E _H	LCD - Data register for Segment 41-40	VRAM20	-	R/W
00063F _H	LCD - Data register for Segment 43-42	VRAM21	-	R/W
000640 _H	LCD - Data register for Segment 45-44	VRAM22	-	R/W
000641 _H	LCD - Data register for Segment 47-46	VRAM23	-	R/W
000642 _H	LCD - Data register for Segment 49-48	VRAM24	-	R/W
000643 _H	LCD - Data register for Segment 51-50	VRAM25	-	R/W
000644 _H	LCD - Data register for Segment 53-52	VRAM26	-	R/W
000645 _H	LCD - Data register for Segment 55-54	VRAM27	-	R/W
000646 _H	LCD - Data register for Segment 57-56	VRAM28	-	R/W
000647 _H	LCD - Data register for Segment 59-58	VRAM29	-	R/W
000648 _H	LCD - Data register for Segment 61-60	VRAM30	-	R/W
000649 _H	LCD - Data register for Segment 63-62	VRAM31	-	R/W
00064A _H	LCD - Data register for Segment 65-64	VRAM32	-	R/W
00064B _H - 00065F _H	Reserved	-	-	-
000660 _H	Peripheral Resource Relocation Register 10	PRRR10	-	R/W
000661 _H	Peripheral Resource Relocation Register 11	PRRR11	-	R/W
000662 _H	Peripheral Resource Relocation Register 12	PRRR12	-	R/W
000663 _H	Peripheral Resource Relocation Register 13	PRRR13	-	W
000664 _H - 0006DF _H	Reserved	-	-	-
0006E0 _H	External Bus - Area configuration register 0 Low	EACL0	EAC0	R/W
0006E1 _H	External Bus - Area configuration register 0 High	EACH0	-	R/W
0006E2 _H	External Bus - Area configuration register 1 Low	EACL1	EAC1	R/W
0006E3 _H	External Bus - Area configuration register 1 High	EACH1	-	R/W
0006E4 _H	External Bus - Area configuration register 2 Low	EACL2	EAC2	R/W
0006E5 _H	External Bus - Area configuration register 2 High	EACH2	-	R/W
0006E6 _H	External Bus - Area configuration register 3 Low	EACL3	EAC3	R/W
0006E7 _H	External Bus - Area configuration register 3 High	EACH3	-	R/W
0006E8 _H	External Bus - Area configuration register 4 Low	EACL4	EAC4	R/W

I/O map MB96(F)38x (Sheet 26 of 30)

Address	Register	Abbreviation 8-bit access	Abbreviation 16-bit access	Access
000746 _H	CAN0 - IF2 Mask 2 Register Low	IF2MSK2L0	IF2MSK20	R/W
000747 _H	CAN0 - IF2 Mask 2 Register High	IF2MSK2H0	-	R/W
000748 _H	CAN0 - IF2 Arbitration 1 Register Low	IF2ARB1L0	IF2ARB10	R/W
000749 _H	CAN0 - IF2 Arbitration 1 Register High	IF2ARB1H0	-	R/W
00074A _H	CAN0 - IF2 Arbitration 2 Register Low	IF2ARB2L0	IF2ARB20	R/W
00074B _H	CAN0 - IF2 Arbitration 2 Register High	IF2ARB2H0	-	R/W
00074C _H	CAN0 - IF2 Message Control Register Low	IF2MCTRL0	IF2MCTR0	R/W
00074D _H	CAN0 - IF2 Message Control Register High	IF2MCTRH0	-	R/W
00074E _H	CAN0 - IF2 Data A1 Low	IF2DTA1L0	IF2DTA10	R/W
00074F _H	CAN0 - IF2 Data A1 High	IF2DTA1H0	-	R/W
000750 _H	CAN0 - IF2 Data A2 Low	IF2DTA2L0	IF2DTA20	R/W
000751 _H	CAN0 - IF2 Data A2 High	IF2DTA2H0	-	R/W
000752 _H	CAN0 - IF2 Data B1 Low	IF2DTB1L0	IF2DTB10	R/W
000753 _H	CAN0 - IF2 Data B1 High	IF2DTB1H0	-	R/W
000754 _H	CAN0 - IF2 Data B2 Low	IF2DTB2L0	IF2DTB20	R/W
000755 _H	CAN0 - IF2 Data B2 High	IF2DTB2H0	-	R/W
000756 _H - 00077F _H	Reserved	-	-	-
000780 _H	CAN0 - Transmission Request 1 Register Low	TREQR1L0	TREQR10	R
000781 _H	CAN0 - Transmission Request 1 Register High	TREQR1H0	-	R
000782 _H	CAN0 - Transmission Request 2 Register Low	TREQR2L0	TREQR20	R
000783 _H	CAN0 - Transmission Request 2 Register High	TREQR2H0	-	R
000784 _H - 00078F _H	Reserved	-	-	-
000790 _H	CAN0 - New Data 1 Register Low	NEWDT1L0	NEWDT10	R
000791 _H	CAN0 - New Data 1 Register High	NEWDT1H0	-	R
000792 _H	CAN0 - New Data 2 Register Low	NEWDT2L0	NEWDT20	R
000793 _H	CAN0 - New Data 2 Register High	NEWDT2H0	-	R
000794 _H - 00079F _H	Reserved	-	-	-
0007A0 _H	CAN0 - Interrupt Pending 1 Register Low	INTPND1L0	INTPND10	R
0007A1 _H	CAN0 - Interrupt Pending 1 Register High	INTPND1H0	-	R

2. Opposite phase external clock

- When using an opposite phase external clock, X1 (X1A) must be supplied with a clock signal which has the opposite phase to the X0 (X0A) pins.



14.4 Unused sub clock signal

If the pins X0A and X1A are not connected to an oscillator, a pull-down resistor must be connected on the X0A pin and the X1A pin must be left open.

14.5 Notes on PLL clock mode operation

If the PLL clock mode is selected and no external oscillator is operating or no external clock is supplied, the microcontroller attempts to work with the free oscillating PLL. Performance of this operation, however, cannot be guaranteed.

14.6 Power supply pins (V_{CC}/V_{SS})

It is required that all V_{CC} -level as well as all V_{SS} -level power supply pins are at the same potential. If there is more than one V_{CC} or V_{SS} level, the device may operate incorrectly or be damaged even within the guaranteed operating range.

V_{CC} and V_{SS} must be connected to the device from the power supply with lowest possible impedance.

As a measure against power supply noise, it is required to connect a bypass capacitor of about 0.1 μF between V_{CC} and V_{SS} as close as possible to V_{CC} and V_{SS} pins.

14.7 Crystal oscillator and ceramic resonator circuit

Noise at X0, X1 pins or X0A, X1A pins might cause abnormal operation. It is required to provide bypass capacitors with shortest possible distance to X0, X1 pins and X0A, X1A pins, crystal oscillator (or ceramic resonator) and ground lines, and, to the utmost effort, that the lines of oscillation circuit do not cross the lines of other circuits.

It is highly recommended to provide a printed circuit board art work surrounding X0, X1 pins and X0A, X1A pins with a ground area for stabilizing the operation.

It is highly recommended to evaluate the quartz/MCU or resonator/MCU system at the quartz or resonator manufacturer, especially when using low-Q resonators at higher frequencies.

14.8 Turn on sequence of power supply to A/D converter and analog inputs

It is required to turn the A/D converter power supply (AV_{CC} , $AVRH$, $AVRL$) and analog inputs (ANn) on after turning the digital power supply (V_{CC}) on.

It is also required to turn the digital power off after turning the A/D converter supply and analog inputs off. In this case, the voltage must not exceed $AVRH$ or AV_{CC} (turning the analog and digital power supplies simultaneously on or off is acceptable).

14.9 Pin handling when not using the A/D converter

It is required to connect the unused pins of the A/D converter as $AV_{CC} = V_{CC}$, $AV_{SS} = AVRH = AVRL = V_{SS}$.

14.10 Notes on Power-on

To prevent malfunction of the internal voltage regulator, supply voltage profile while turning the power supply on should be slower than 50 μs from 0.2 V to 2.7 V.

14.11 Stabilization of power supply voltage

If the power supply voltage varies acutely even within the operation safety range of the V_{CC} power supply voltage, a malfunction may occur. The V_{CC} power supply voltage must therefore be stabilized. As stabilization guidelines, the power supply voltage must be stabilized in such a way that V_{CC} ripple fluctuations (peak to peak value) in the commercial frequencies (50 to 60 Hz) fall within 10% of the standard V_{CC} power supply voltage and the transient fluctuation rate becomes 0.1V/ μs or less in instantaneous fluctuation for power supply switching.

15.3 DC characteristics

($T_A = -40^\circ\text{C}$ to 125°C , $V_{CC} = AV_{CC} = 3.0\text{V}$ to 5.5V , $DV_{CC} = 3.0\text{V}$ to 5.5V , $V_{SS} = AV_{SS} = DV_{SS} = 0\text{V}$)

Parameter	Symbol	Pin	Condition	Value			Unit	Remarks
				Min	Typ	Max		
Input H voltage	V_{IH}	Port inputs Pnn_m	CMOS Hysteresis 0.8/0.2 input selected	$0.8 V_{CC}$	-	$(D)V_{CC} + 0.3$	V	
			CMOS Hysteresis 0.7/0.3 input selected	$0.7 V_{CC}$	-	$(D)V_{CC} + 0.3$	V	$(D)V_{CC} \geq 4.5\text{V}$
				$0.74 V_{CC}$	-	$(D)V_{CC} + 0.3$	V	$(D)V_{CC} < 4.5\text{V}$
			AUTOMOTIVE Hysteresis input selected	$0.8 V_{CC}$	-	$(D)V_{CC} + 0.3$	V	
			TTL input selected	2.0	-	$(D)V_{CC} + 0.3$	V	
	V_{IH0F}	X0	External clock in "Fast Clock Input mode"	$0.8 V_{CC}$	-	$V_{CC} + 0.3$	V	Not available in MB96F386xxA/F387xxA
	V_{IH0S}	X0,X1, X0A,X1A	External clock in "oscillation mode"	2.5	-	$V_{CC} + 0.3$	V	
	V_{IHR}	RSTX	-	$0.8 V_{CC}$	-	$V_{CC} + 0.3$	V	CMOS Hysteresis input
Input L voltage	V_{IL}	Port inputs Pnn_m	CMOS Hysteresis 0.8/0.2 input selected	$V_{SS} - 0.3$	-	$0.2 (D)V_{CC}$	V	
			CMOS Hysteresis 0.7/0.3 input selected	$V_{SS} - 0.3$	-	$0.3 (D)V_{CC}$	V	
				$V_{SS} - 0.3$	-	$0.5 (D)V_{CC}$	V	$(D)V_{CC} \geq 4.5\text{V}$
			AUTOMOTIVE Hysteresis input selected	$V_{SS} - 0.3$	-	$0.46 (D)V_{CC}$		$(D)V_{CC} < 4.5\text{V}$
				$V_{SS} - 0.3$	-	0.8	V	
			TTL input selected	$V_{SS} - 0.3$	-	0.8	V	
	V_{ILX0F}	X0	External clock in "Fast Clock Input mode"	$V_{SS} - 0.3$	-	$0.2 V_{CC}$	V	Not available in MB96F386xxA/F387xxA
	V_{ILX0S}	X0,X1, X0A,X1A	External clock in "oscillation mode"	$V_{SS} - 0.3$	-	0.4	V	
	V_{ILR}	RSTX	-	$V_{SS} - 0.3$	-	$0.2 V_{CC}$	V	CMOS Hysteresis input
	V_{ILM}	MD2-MD0	-	$V_{SS} - 0.3$	-	$V_{SS} + 0.3$	V	

($T_A = -40^{\circ}\text{C}$ to 125°C , $V_{CC} = AV_{CC} = 3.0\text{V}$ to 5.5V , $DV_{CC} = 3.0\text{V}$ to 5.5V , $V_{SS} = AV_{SS} = DV_{SS} = 0\text{V}$)

Parameter	Symbol	Condition (at T _A)		Value			Remarks
				Typ	Max	Unit	
Power supply current in Sleep modes*	I _{CCSMAIN}	Main Sleep mode with CLKS1/2 = CLKP1/2 = 4MHz (CLKPLL, CLKSC and CLKRC stopped)	+25°C	1.5	1.8	mA	MB96F386/F387
			+125°C	2	4.5		
			+25°C	1.6	2	mA	MB96F388/F389
			+125°C	2.1	4.2		
			+25°C	1.5	1.8	mA	MB96384/385/F385
			+125°C	2	3.3		
	I _{CCSRCH}	RC Sleep mode with CLKS1/2 = CLKP1/2 = 2MHz (CLKMC, CLKPLL and CLKSC stopped)	+25°C	0.9	1.4	mA	MB96F386/F387
			+125°C	1.5	4		
			+25°C	0.9	1.4	mA	MB96F388/F389
			+125°C	1.5	3.5		
			+25°C	0.9	1.4	mA	MB96384/385/F385
			+125°C	1.5	2.8		

($T_A = -40^{\circ}\text{C}$ to 125°C , $V_{CC} = AV_{CC} = 3.0\text{V}$ to 5.5V , $DV_{CC} = 3.0\text{V}$ to 5.5V , $V_{SS} = AV_{SS} = DV_{SS} = 0\text{V}$)

Parameter	Symbol	Condition (at T _A)	Value			Remarks	
			Typ	Max	Unit		
Power supply current in Sleep modes*	I _{CCSRCL}	RC Sleep mode with CLKS1/2 = CLKP1/2 = 100kHz, SMCR:LPMSS = 0 (CLKMC, CLKPLL and CLKSC stopped. Voltage regulator in high power mode)	+25°C	0.3	0.5	mA	MB96F386/F387
			+125°C	0.8	3.4		
			+25°C	0.3	0.5	mA	MB96F388/F389
			+125°C	0.8	2.8		
			+25°C	0.3	0.5	mA	MB96384/385/F385
			+125°C	0.8	2		
		RC Sleep mode with CLKS1/2 = CLKP1/2 = 100kHz, SMCR:LPMSS = 1 (CLKMC, CLKPLL and CLKSC stopped. Voltage regulator in low power mode)	+25°C	0.06	0.15	mA	MB96F386/F387
			+125°C	0.56	3		
			+25°C	0.06	0.15	mA	MB96F388/F389
			+125°C	0.56	2.4		
			+25°C	0.06	0.15	mA	MB96384/385/F385
			+125°C	0.56	1.6		
	I _{CCSSUB}	Sub Sleep mode with CLKS1/2 = CLKP1/2 = 32kHz (CLKMC, CLKPLL and CLKRC stopped)	+25°C	0.04	0.12	mA	MB96F386/F387
			+125°C	0.54	2.9		
+25°C			0.04	0.12	mA	MB96F388/F389	
+125°C			0.54	2.3			
+25°C			0.04	0.12	mA	MB96384/385/F385	
+125°C			0.54	1.55			
Power supply current in Timer modes*	I _{CCTPLL}	PLL Timer mode with CLKMC = 4MHz, CLKPLL = 48MHz (CLKRC and CLKSC stopped. Core voltage at 1.9V)	+25°C	1.6	2	mA	MB96F386/F387
			+125°C	2.1	4.8		
			+25°C	1.6	2	mA	MB96F388/F389
			+125°C	2.1	4.2		
			+25°C	1.6	2	mA	MB96384/385/F385
			+125°C	2.1	3.5		

($T_A = -40^{\circ}\text{C}$ to 125°C , $V_{CC} = AV_{CC} = 3.0\text{V}$ to 5.5V , $DV_{CC} = 3.0\text{V}$ to 5.5V , $V_{SS} = AV_{SS} = DV_{SS} = 0\text{V}$)

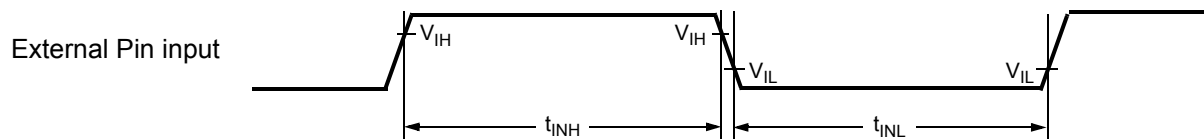
Parameter	Symbol	Condition (at T_A)		Value			Remarks
				Typ	Max	Unit	
Power supply current in Timer modes*	I_{CCTRCL}	RC Timer mode with CLKRC = 100kHz, SMCR:LPMSS = 0 (CLKMC, CLKPLL and CLKSC stopped. Voltage regulator in high power mode)	+25°C	0.3	0.45	mA	MB96F386/F387
			+125°C	0.8	3.2		
			+25°C	0.3	0.45	mA	MB96F386/F387
			+125°C	0.8	2.6		
			+25°C	0.3	0.45	mA	MB96384/385/F385
			+125°C	0.8	1.95		
		RC Timer mode with CLKRC = 100kHz, SMCR:LPMSS = 1 (CLKMC, CLKPLL and CLKSC stopped. Voltage regulator in low power mode)	+25°C	0.05	0.1	mA	MB96F386/F387
			+125°C	0.55	2.8		
			+25°C	0.05	0.1	mA	MB96F388/F389
			+125°C	0.55	2.2		
			+25°C	0.05	0.1	mA	MB96384/385/F385
			+125°C	0.55	1.55		
	I_{CCTSUB}	Sub Timer mode with CLKSC = 32kHz (CLKMC, CLKPLL and CLKRC stopped)	+25°C	0.03	0.1	mA	MB96F386/F387
			+125°C	0.53	2.8		
			+25°C	0.03	0.1	mA	MB96F388/F389
			+125°C	0.53	2.2		
			+25°C	0.03	0.1	mA	MB96384/385/F385
			+125°C	0.53	1.55		

External Input timing

($T_A = -40^{\circ}\text{C}$ to 125°C , $V_{CC} = AV_{CC} = 3.0\text{V}$ to 5.5V , $DV_{CC} = 3.0\text{V}$ to 5.5V , $V_{SS} = AV_{SS} = DV_{SS} = 0\text{V}$)

Parameter	Symbol	Pin	Condition	Value		Unit	Used Pin input function
				Min	Max		
Input pulse width	t_{INH} t_{INL}	INTn(_R)	—	200	—	ns	External Interrupt
		NMI(_R)					NMI
		Pnn_m		$2 \cdot t_{CLKP1} + 200$ ($t_{CLKP1} = 1/f_{CLKP1}$)	—	ns	General Purpose IO
		TINn(_R)					Reload Timer
		TTGn(_R)					PPG Trigger input
		ADTG(_R)					AD Converter Trigger
		FRCKn(_R)					Free Running Timer external clock
		INn(_R)					Input Capture

Note : Relocated Resource Inputs have same characteristics



Bus Timing (Read)
 $(T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}, V_{CC} = 5.0\text{ V} \pm 10\%, V_{SS} = 0.0\text{ V}, I_{Odrive} = 5\text{mA}, C_L = 50\text{pF})$

Parameter	Symbol	Pin	Conditions	Value		Unit	Remarks
				Min	Max		
ALE pulse width (multiplexed)	t_{LHLL}	ALE	EACL:STS=0 and EACL:ACE=0	$t_{CYC}/2 - 5$	—	ns	EBM:NMS = 0
			EACL:STS=1	$t_{CYC} - 5$	—		
			EACL:STS=0 and EACL:ACE=1	$3t_{CYC}/2 - 5$	—		
Valid address ⇒ ALE ↓ time (multiplexed)	t_{AVLL}	ALE, A[23:16],	EACL:STS=0 and EACL:ACE=0	$t_{CYC} - 15$	—	ns	
			EACL:STS=1 and EACL:ACE=0	$3t_{CYC}/2 - 15$	—		
			EACL:STS=0 and EACL:ACE=1	$2t_{CYC} - 15$	—		
			EACL:STS=1 and EACL:ACE=1	$5t_{CYC}/2 - 15$	—		
	t_{ADVLL}	ALE,AD[15:0]	EACL:STS=0 and EACL:ACE=0	$t_{CYC}/2 - 15$	—	ns	
			EACL:STS=1 and EACL:ACE=0	$t_{CYC} - 15$	—		
			EACL:STS=0 and EACL:ACE=1	$3t_{CYC}/2 - 15$	—		
			EACL:STS=1 and EACL:ACE=1	$2t_{CYC} - 15$	—		
ALE ↓ ⇒ Address valid time (multiplexed)	t_{LLAX}	ALE, AD[15:0]	EACL:STS=0	$t_{CYC}/2 - 15$	—	ns	
			EACL:STS=1	-15	—		
Valid address ⇒ RDX ↓ time (non-multiplexed)	t_{AVRL}	RDX, A[23:0]	EBM:NMS= 1	$t_{CYC}/2 - 15$	—	ns	
Valid address ⇒ RDX ↓ time (multiplexed)	t_{AVRL}	RDX, A[23:16]	EACL:ACE=0 EBM:NMS=0	$3t_{CYC}/2 - 15$	—	ns	
			EACL:ACE=1 EBM:NMS=0	$5t_{CYC}/2 - 15$	—		
	t_{ADVRL}	RDX, AD[15:0]	EACL:ACE=0 EBM:NMS=0	$t_{CYC} - 15$	—	ns	
			EACL:ACE=1 EBM:NMS=0	$2t_{CYC} - 15$	—		
Valid address ⇒ Valid data input (non-multiplexed)	t_{AVDV}	A[23:0], AD[15:0]	EBM:NMS= 1	—	$2t_{CYC} - 55$	ns	w/o cycle extension

($T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{CC} = 3.0$ to 4.5V , $V_{SS} = 0.0\text{V}$, $I_{O_{drive}} = 5\text{mA}$, $C_L = 50\text{pF}$)

Parameter	Symbol	Pin	Conditions	Value		Unit	Remarks
				Min	Max		
Valid address ⇒ Valid data input (multiplexed)	t_{AVDV}	A[23:16], AD[15:0]	EACL:ACE=0 EBM:NMS=0	—	$3t_{CYC} - 60$	ns	w/o cycle extension
			EACL:ACE=1 EBM:NMS=0	—	$4t_{CYC} - 60$		
	t_{AD-VDV}	AD[15:0]	EACL:ACE=0 EBM:NMS=0	—	$5t_{CYC}/2 - 60$	ns	w/o cycle extension
			EACL:ACE=1 EBM:NMS=0	—	$7t_{CYC}/2 - 60$		
RDX pulse width	t_{RLRH}	RDX	—	$3t_{CYC}/2 - 8$	—	ns	w/o cycle extension
RDX ↓ ⇒ Valid data input	t_{RLDV}	RDX, AD[15:0]	—	—	$3t_{CYC}/2 - 55$	ns	w/o cycle extension
RDX ↑ ⇒ Data hold time	t_{RHDX}	RDX, AD[15:0]	—	0	—	ns	
Address valid ⇒ Data hold time	t_{AXDX}	A[23:0]	—	0	—	ns	
RDX ↑ ⇒ ALE ↑ time	t_{RHLH}	RDX, ALE	EACL:STS=1 and EACL:ACE=1	$3t_{CYC}/2 - 15$	—	ns	
			other ECL:STS, EACL:ACE setting	$t_{CYC}/2 - 15$	—		
Valid address ⇒ ECLK ↑ time	t_{AVCH}	A[23:0], ECLK	—	$t_{CYC} - 20$	—	ns	
	t_{AD-VCH}	AD[15:0], ECLK		$t_{CYC}/2 - 20$	—		
RDX ↓ ⇒ ECLK ↑ time	t_{RLCH}	RDX, ECLK	—	$t_{CYC}/2 - 15$	—	ns	
ALE ↓ ⇒ RDX ↓ time	t_{LLRL}	ALE, RDX	EACL:STS=0	$t_{CYC}/2 - 15$	—	ns	
			EACL:STS=1	- 15	—		
ECLK ↑ ⇒ Valid data input	t_{CHDV}	AD[15:0], ECLK	—	—	$t_{CYC} - 55$	ns	

Ready Input Timing

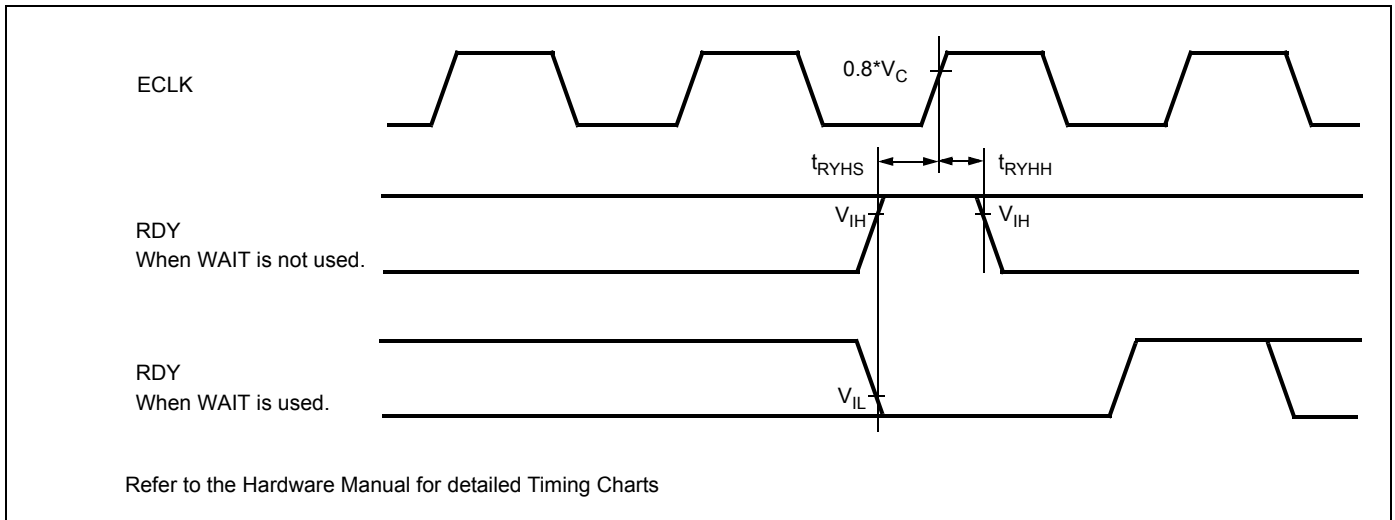
($T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{CC} = 5.0\text{ V} \pm 10\%$, $V_{SS} = 0.0\text{ V}$, $I_{Odrive} = 5\text{mA}$, $C_L = 50\text{pF}$)

Parameter	Symbol	Pin	Test Condition	Rated Value		Units	Remarks
				Min	Max		
RDY setup time	t_{RYHS}	RDY	—	35	—	ns	
RDY hold time	t_{RYHH}	RDY		0	—	ns	

($T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{CC} = 3.0$ to 4.5V , $V_{SS} = 0.0\text{ V}$, $I_{Odrive} = 5\text{mA}$, $C_L = 50\text{pF}$)

Parameter	Symbol	Pin	Test Condition	Rated Value		Units	Remarks
				Min	Max		
RDY setup time	t_{RYHS}	RDY	—	45	—	ns	
RDY hold time	t_{RYHH}	RDY		0	—	ns	

Note : If the RDY setup time is insufficient, use the auto-ready function.



15.5 Analog Digital Converter

($T_A = -40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$, $3.0\text{ V} \leq \text{AVRH} - \text{AVRL}$, $V_{CC} = \text{AV}_{CC} = 3.0\text{V}$ to 5.5V , $V_{SS} = \text{AV}_{SS} = 0\text{V}$)

Parameter	Symbol	Pin	Value			Unit	Remarks
			Min	Typ	Max		
Resolution	-	-	-	-	10	bit	
Total error	-	-	-3	-	+3	LSB	
Nonlinearity error	-	-	-2.5	-	+2.5	LSB	
Differential nonlinearity error	-	-	-1.9	-	+1.9	LSB	
Zero reading voltage	V_{OT}	ANn	AVRL-1.5 LSB	AVRL+0.5 LSB	AVRL+2.5 LSB	V	
Full scale reading voltage	V_{FST}	ANn	AVRH-3.5 LSB	AVRH-1.5 LSB	AVRH+0.5 LSB	V	
Compare time	-	-	1.0	-	16,500	μs	$4.5\text{V} \leq \text{AV}_{CC} \leq 5.5\text{V}$
			2.0	-	-	μs	$3.0\text{V} \leq \text{AV}_{CC} < 4.5\text{V}$
Sampling time	-	-	0.5	-	-	μs	$4.5\text{V} \leq \text{AV}_{CC} \leq 5.5\text{V}$
			1.2	-	-	μs	$3.0\text{V} \leq \text{AV}_{CC} < 4.5\text{V}$
Analog port input current	I_{AIN}	ANn	-3	-	+3	μA	$\text{AV}_{SS}, \text{AVRL} < V_I < \text{AV}_{CC}, \text{AVRH}$
Analog input leakage current (during conversion)	I_{AIN}	ANn	-1	-	+1	μA	$T_A = 25\text{ }^{\circ}\text{C}, \text{AV}_{SS}, \text{AVRL} < V_I < \text{AV}_{CC}, \text{AVRH}$
			-3	-	+3	μA	$T_A = 125\text{ }^{\circ}\text{C}, \text{AV}_{SS}, \text{AVRL} < V_I < \text{AV}_{CC}, \text{AVRH}$
Analog input voltage range	V_{AIN}	ANn	AVRL	-	AVRH	V	
Reference voltage range	AVRH	AVRH/AVRH2	0.75 AV_{CC}	-	AV_{CC}	V	
	AVRL	AVRL	AV_{SS}	-	0.25 AV_{CC}	V	
Power supply current	I_A	AV_{CC}	-	2.5	5	mA	A/D Converter active
	I_{AH}	AV_{CC}	-	-	5	μA	A/D Converter not operated
Reference voltage current	I_R	AVRH/AVRL	-	0.7	1	mA	A/D Converter active
	I_{RH}	AVRH/AVRL	-	-	5	μA	A/D Converter not operated
Offset between input channels	-	ANn	-	-	4	LSB	

Note: The accuracy gets worse as $|\text{AVRH} - \text{AVRL}|$ becomes smaller.

15.7 Low Voltage Detector characteristics

($T_A = -40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$, $V_{CC} = AV_{CC} = 3.0\text{V} - 5.5\text{V}$, $V_{SS} = AV_{SS} = 0\text{V}$)

Parameter	Symbol	Value		Unit	Remarks
		Min	Max		
Stabilization time	$T_{LVDSTAB}$	-	75	μs	After power-up or change of detection level
Level 0	V_{DL0}	2.7	2.9	V	CILCR:LVL[3:0]="0000"
Level 1	V_{DL1}	2.9	3.1	V	CILCR:LVL[3:0]="0001"
Level 2	V_{DL2}	3.1	3.3	V	CILCR:LVL[3:0]="0010"
Level 3	V_{DL3}	3.5	3.75	V	CILCR:LVL[3:0]="0011"
Level 4	V_{DL4}	3.6	3.85	V	CILCR:LVL[3:0]="0100"
Level 5	V_{DL5}	3.7	3.95	V	CILCR:LVL[3:0]="0101"
Level 6	V_{DL6}	3.8	4.05	V	CILCR:LVL[3:0]="0110"
Level 7	V_{DL7}	3.9	4.15	V	CILCR:LVL[3:0]="0111"
Level 8	V_{DL8}	4.0	4.25	V	CILCR:LVL[3:0]="1000"
Level 9	V_{DL9}	4.1	4.35	V	CILCR:LVL[3:0]="1001"
Level 10	V_{DL10}	not used			
Level 11	V_{DL11}	not used			
Level 12	V_{DL12}	not used			
Level 13	V_{DL13}	not used			
Level 14	V_{DL14}	not used			
Level 15	V_{DL15}	not used			

CILCR:LVL[3:0] are the low voltage detector level select bits of the CILCR register.

Levels 10 to 15 are not used in this device.

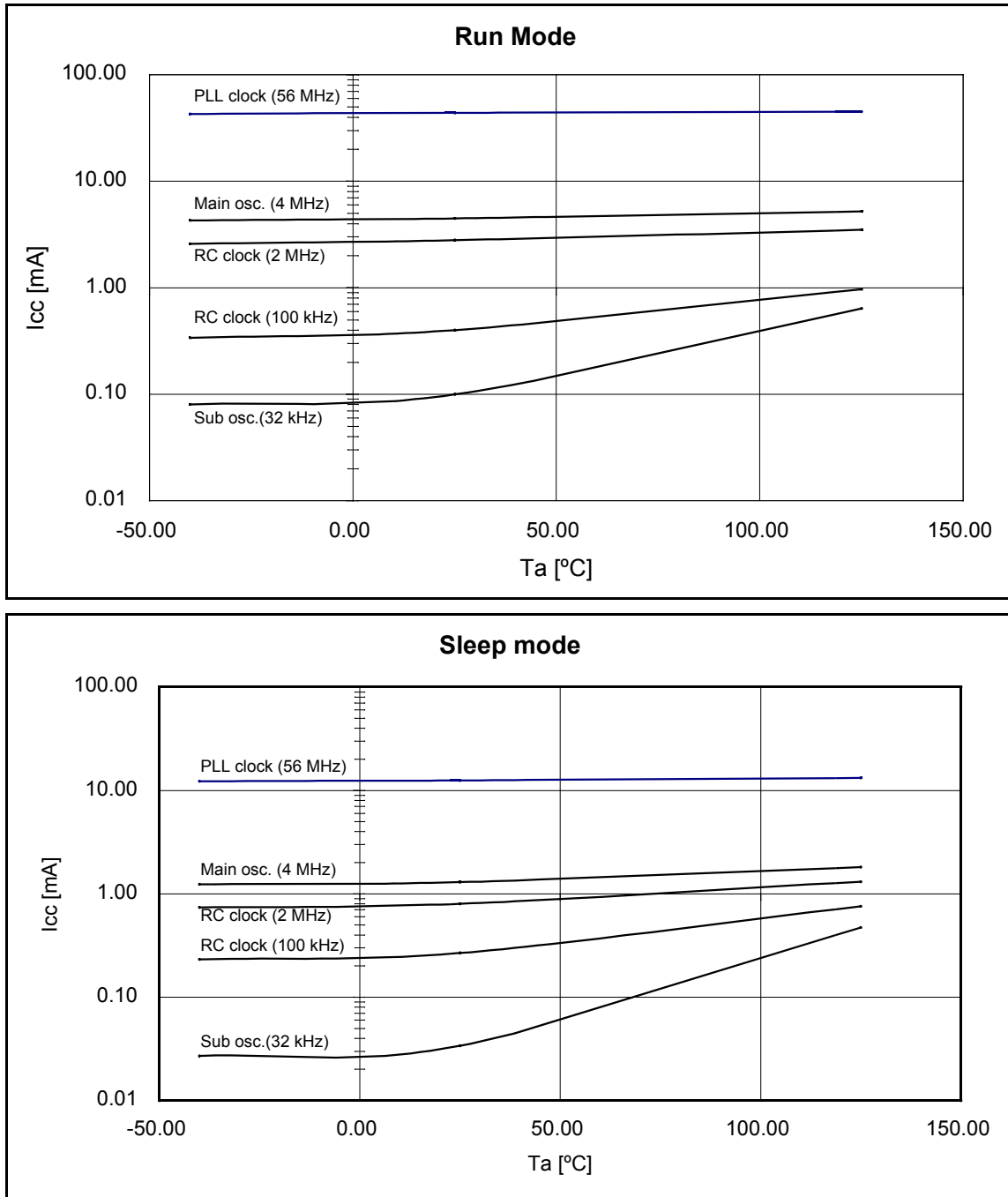
For correct detection, the slope of the voltage level must satisfy $\left| \frac{dV}{dt} \right| \leq 0.004 \frac{\text{V}}{\mu\text{s}}$.

Faster variations are regarded as noise and may not be detected.

The functional operation of the MCU is guaranteed down to the minimum low voltage detection level of $V_{CC} = 2.7\text{V}$. The electrical characteristics however are only valid in the specified range (usually down to 3.0V).

16. Example Characteristics

The diagrams below show the characteristics of one measured sample with typical process parameters.



18. Ordering Information

Part number	Flash/ROM	Subclock	Persistent Low Voltage Reset	Package
MB96384YSB PMC-GSE2 *1	ROM (128KB)	No	Yes	120 pin Plastic LQFP (FPT-120P-M21)
MB96384RSB PMC-GSE2 *1			No	
MB96384YWB PMC-GSE2 *1		Yes	Yes	
MB96384RWB PMC-GSE2 *1			No	
MB96385YSB PMC-GSE2 *1	ROM (160KB)	No	Yes	120 pin Plastic LQFP (FPT-120P-M21)
MB96385RSB PMC-GSE2 *1			No	
MB96385YWB PMC-GSE2 *1		Yes	Yes	
MB96385RWB PMC-GSE2 *1			No	
MB96F385YSA PMC-GSE2 *1	Flash A (160KB)	No	Yes	120 pin Plastic LQFP (FPT-120P-M21)
MB96F385RSA PMC-GSE2 *1			No	
MB96F385YWA PMC-GSE2 *1		Yes	Yes	
MB96F385RWA PMC-GSE2 *1			No	
MB96F386YSB PMC-GSE2	Flash A (288KB)	No	Yes	120 pin Plastic LQFP (FPT-120P-M21)
MB96F386RSB PMC-GSE2			No	
MB96F386YWB PMC-GSE2		Yes	Yes	
MB96F386RWB PMC-GSE2			No	
MB96F387YSB PMC-GSE2	Flash A (416KB)	No	Yes	120 pin Plastic LQFP (FPT-120P-M21)
MB96F387RSB PMC-GSE2			No	
MB96F387YWB PMC-GSE2		Yes	Yes	
MB96F387RWB PMC-GSE2			No	
MB96F388TSA PMC-GSE2 *1	Flash A (544KB) Flash B (32KB)	No	Yes	120 pin Plastic LQFP (FPT-120P-M21)
MB96F388HSA PMC-GSE2 *1			No	
MB96F388TWA PMC-GSE2 *1		Yes	Yes	
MB96F388HWA PMC-GSE2 *1			No	
MB96F389YSA PMC-GSE2 *1	Flash A (544KB) Flash B (288KB)	No	Yes	120 pin Plastic LQFP (FPT-120P-M21)
MB96F389RSA PMC-GSE2 *1			No	
MB96F389YWA PMC-GSE2 *1		Yes	Yes	
MB96F389RWA PMC-GSE2 *1			No	
MB96V300BRB-ES (for evaluation)	Emulated by ext. RAM	Yes	No	416 pin Plastic BGA (BGA-416P-M02)

*1: These devices are under development and specification is preliminary. These products under development may change its specification without notice.

This datasheet is also valid for the following outdated devices:

MB96F386YSA, MB96F386RSA, MB96F386YWA, MB96F386RWA,
MB96F387YSA, MB96F387RSA, MB96F387YWA, MB96F387RWA

19. Revision History

Spanson Publication Number: **DS07-13803-2E**

Revision	Date	Modification
Prelim 1	2007-05-2	Creation
Prelim 2	2007-05-24	Electrical characteristics and memory description updates
Prelim 3	2007-08-09	Typo errors corrections, Flash memory programming interface update
Prelim 4	2007-08-31	Update of DC characteristics. new MB96F388 and MB96F389 added. LVD chapter added as well as an example characteristics chapter
Prelim 5	2007-09-06	Updates of the DC characteristics, interrupt vector table update, update of the LVD characteristics
Prelim 6	2007-11-14	Memory map for external bus modified. Modifications of the drawing of the pin circuits. Electrical characteristics updates. Rephrasing and typos corrections. Add Slew rate high current outputs chapter. Modification of the block diagram. Memory map modified for Flash. RAM memory map added. Pin circuit type corrected. Type L IO is now included.
Prelim 7	2007-12-12	Memory IO map modified New Flash/ROM configuration presentation Ordering information: MB96300B used as reference. Block diagram modified to included relocated pins. Main Flash becomes Flash memory A and Satellite flash becomes Flash memory B
Prelim 8	2008-02-04	• Devices under development added: MB96384/385/F385/F388/F389 • Block diagram corrected (existing resource pins) • Pin assignment: TTG8 -> TTG7 • Pin function table corrected • I/O circuit type diagrams corrected • Memory map cleaned up • "Flash sector configuration" replaced by corrected "User ROM Memory map for Flash devices", "ROM configuration" replaced by "User ROM Memory map for Mask ROM devices" • IO map table regenerated: - Port register: Naming style corrected - Memory control registers renamed (Main/Sat -> A/B) - addresses after 000BFFh removed • Absolute maximum ratings: Pd and Ta specified more precisely • Run and Sleep mode currents: more conditions added (1WS settings) • Run mode current spec in 48/24MHz mode corrected • Maximum CLKP2 frequency for MB96F386/F387 corrected • High current port input capacitance added • External bus timings: missing conditions added and readability improved • Alarm comparator spec updated (transition voltages defined) • MB96V300A removed • Ordering information updated • Typos and formatting corrected

Revision	Date	Modification
9	2009-01-09	• Format adjusted to official Fujitsu Microelectronics datasheet standard (mainly style changes and official notes and disclaimer added) • Numbering of Electrical Characteristics subchapters automated • Note about devices under development modified • I/O map: Note added about reserved addresses • Serial programming interface: Note about handshaking pins improved • ICCPLL for CLKS1/2=80MHz, CLKB=40MHz (F388/F389) increased by 5mA • ICCSPLL for CLKS1/2=80MHz, CLKB=40MHz (F388/F389) increased by 0.8mA (typ) and 1.3mA (max) • Updated ordering information: MB96384/385**A -> MB96384/385**B • Package code of MB96V300 corrected in ordering information • Internal LCD divider resistance value corrected: Typ 35kOhm -> 40kOhm, Max 50kOhm -> 65kOhm • Run and Sleep mode currents of ROM devices (MB96384/385) reduced • Added voltage condition to pull-up resistance and LCD divide resistance spec • Lineup: Term "Data Flash" replaced by "independent 32KB Flash" • Ordering information: column "Independent 32KB Data Flash" replaced by new column "Flash/ROM", column "Remarks" removed • Official package dimension drawing with additional notes added • Empty pages removed • MB96384/385 and MB96F385/F388/F389 separated in DC spec and currents of these devices adjusted according to first evaluation results • Alarm comparator: Power supply current max values increased, comparison time reduced, mode transition time and power-up stabilization time newly added • Handling devices: Notes added about Serial communication and about using ceramic resonators. • Feature list and AC Characteristics: 16MHz maximum frequency is valid for crystal oscillators. For resonators, maximum frequency depends on Q-factor • AC characteristics: PLL phase skew spec added, CLKVCO min=64MHz • VOL3 spec improved: spec valid for 3mA load for full Vcc range • C-Pin cap spec updated: 4.7uF-10uF capacitor with tolerance permitted • "Preliminary" watermark removed

NOTE: Please see "Document History" about later revised information.